BC817; BC817W; BC337 45 V, 500 mA NPN general-purpose transistors Rev. 06 — 17 November 2009

Product data sheet

Product profile

1.1 General description

NPN general-purpose transistors.

Table 1. **Product overview**

Type number	Package		PNP complement
	NXP	JEITA	_
BC817	SOT23	-	BC807
BC817W	SOT323	SC-70	BC807W
BC337[1]	SOT54 (TO-92)	SC-43A	BC327

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- High current
- Low voltage

1.3 Applications

■ General-purpose switching and amplification

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base; I _C = 10 mA		-	-	45	V
I _C	collector current (DC)			-	-	500	mΑ
I _{CM}	peak collector current			-	-	1	Α
h _{FE}	DC current gain	$I_C = 100 \text{ mA};$	<u>[1]</u>	-	-	-	
	BC817; BC817W; BC337	V _{CE} = 1 V		100	-	600	
	BC817-16; BC817-16W; BC337-16			100	-	250	
	BC817-25; BC817-25W; BC337-25			160	-	400	
	BC817-40; BC817-40W; BC337-40			250	-	600	

^[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.



2. Pinning information

Table 3.	Pinning		
Pin	Description	Simplified outline	Symbol
SOT23			
1	base		_
2	emitter	3	3
3	collector		1 —
		1 2	2
			sym021
SOT323			
1	base		
2	emitter	3	3
3	collector		1 —
			13
			2
		1 2	sym021
		sot323_so	
SOT54			
1	emitter		•
2	base		3
3	collector		2 —
			. j
		001aab347	1 sym026
SOT54A			Symozo
1	emitter		
2	base		3
3	collector		
J	Collector		2 —
		001aab348	1
		00.440040	sym026
SOT54 va	riant		
1	emitter		
2	base		3
3	collector		2 —
			')
		001aab447	1 sym026
			sylli020

3. Ordering information

Table 4. Ordering information

Type number[1]	Package	Package		
	Name	Description	Version	
BC817	-	plastic surface mounted package; 3 leads	SOT23	
BC817W	SC-70	plastic surface mounted package; 3 leads	SOT323	
BC337[2]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54	

^[1] Valid for all available selection groups.

4. Marking

Table 5. Marking codes

Table 3. Marking codes	
Type number	Marking code ^[1]
BC817	6D*
BC817-16	6A*
BC817-25	6B*
BC817-40	6C*
BC817W	6D*
BC817-16W	6A*
BC817-25W	6B*
BC817-40W	6C*
BC337	C337
BC337-16	C33716
BC337-25	C33725
BC337-40	C33740

^{[1] * = -:} made in Hong Kong

^[2] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	50	V
V_{CEO}	collector-emitter voltage	open base; I _C = 10 mA	-	45	V
V_{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current (DC)		-	500	mA
I _{CM}	peak collector current		-	1	Α
I _{BM}	peak base current		-	200	mA
P _{tot}	total power dissipation				
	BC817	$T_{amb} \le 25 ^{\circ}C$	[1][2]	250	mW
	BC817W	$T_{amb} \le 25 ^{\circ}C$	[1][2]	200	mW
	BC337	$T_{amb} \le 25 ^{\circ}C$	[1][2]	625	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C

^[1] Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient					
	BC817	$T_{amb} \le 25 ^{\circ}C$	[1][2] _	-	500	K/W
	BC817W	$T_{amb} \le 25 ^{\circ}C$	[1][2]	-	625	K/W
	BC337	$T_{amb} \le 25 ^{\circ}C$	[1][2]	-	200	K/W

^[1] Transistor mounted on an FR4 printed-circuit board, single-sided copper, tin-plated and standard footprint.

^[2] Valid for all available selection groups.

^[2] Valid for all available selection groups.

7. Characteristics

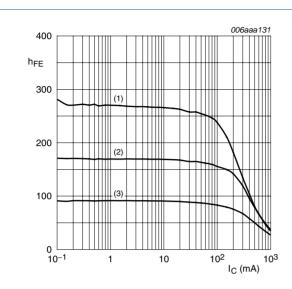
Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$I_E = 0 A; V_{CB} = 20 V$	-	-	100	nA
		$I_E = 0 \text{ A}; V_{CB} = 20 \text{ V};$ $T_j = 150 ^{\circ}\text{C}$	-	-	5	μΑ
I _{EBO}	emitter-base cut-off current	$I_C = 0 A; V_{EB} = 5 V$	-	-	100	nA
h _{FE}	DC current gain $I_C = 100 \text{ mA}; V_{CE} = 1 \text{ V}$		<u>[1]</u>			
	BC817; BC817W; BC337		100	-	600	
	BC817-16; BC817-16W; BC337-16		100	-	250	
	BC817-25; BC817-25W; BC337-25		160	-	400	
	BC817-40; BC817-40W; BC337-40		250	-	600	
h _{FE}	DC current gain	$I_C = 500 \text{ mA}; V_{CE} = 1 \text{ V}$	<u>[1]</u> 40	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 500 \text{ mA}; I_B = 50 \text{ mA}$	<u>[1]</u> -	-	700	mV
V _{BE}	base-emitter voltage	$I_C = 500 \text{ mA}; V_{CE} = 1 \text{ V}$	[2] -	-	1.2	V
C _c	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = 10 \text{ V};$ f = 1 MHz	-	3	-	pF
f _T	transition frequency	$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V};$ f = 100 MHz	100	-	-	MHz

^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02.$

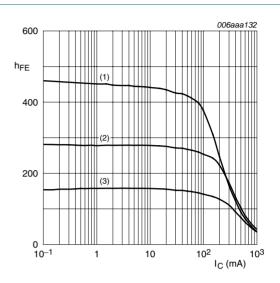
^[2] V_{BE} decreases by approximately 2 mV/K with increasing temperature.



$$V_{CE} = 1 V$$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

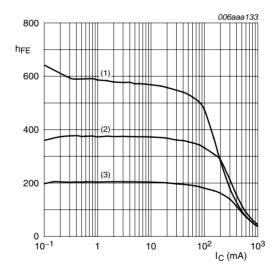
Fig 1. Selection -16: DC current gain as a function of collector current; typical values



$$V_{CE} = 1 V$$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

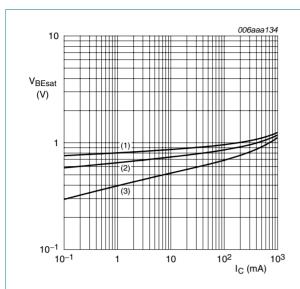
Fig 2. Selection -25: DC current gain as a function of collector current; typical values



$$V_{CE} = 1 V$$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

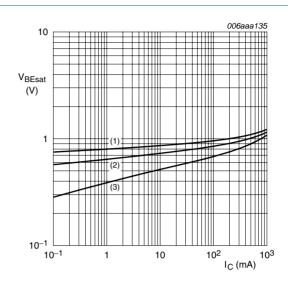
Fig 3. Selection -40: DC current gain as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

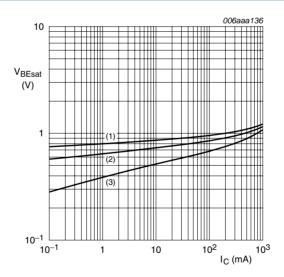
Fig 4. Selection -16: Base-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

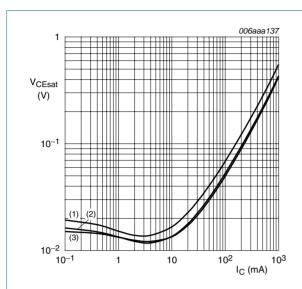
Fig 5. Selection -25: Base-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = -55 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = 150 \, ^{\circ}C$

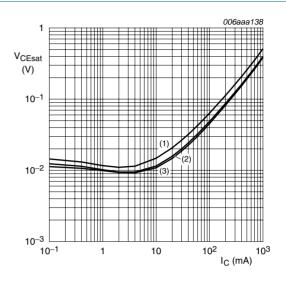
Fig 6. Selection -40: Base-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

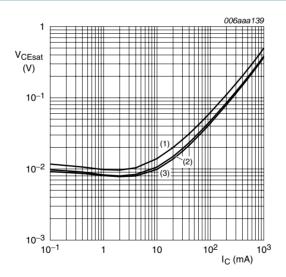
Fig 7. Selection -16: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

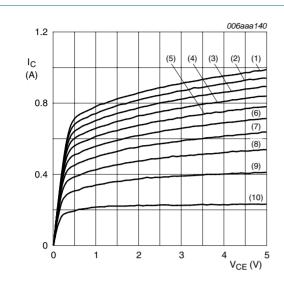
Fig 8. Selection -25: Collector-emitter saturation voltage as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 10$$

- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -55 \, ^{\circ}C$

Fig 9. Selection -40: Collector-emitter saturation voltage as a function of collector current; typical values

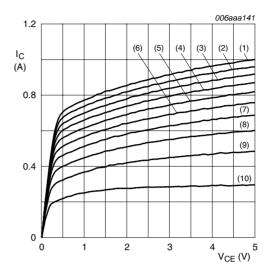


T_{amb} = 25 °C

- (1) $I_B = 16.0 \text{ mA}$
- (2) $I_B = 14.4 \text{ mA}$
- (3) $I_B = 12.8 \text{ mA}$
- (4) $I_B = 11.2 \text{ mA}$
- (5) $I_B = 9.6 \text{ mA}$
- (6) $I_B = 8.0 \text{ mA}$
- (7) $I_B = 6.4 \text{ mA}$
- (8) $I_B = 4.8 \text{ mA}$ (9) $I_B = 3.2 \text{ mA}$
- (10) $I_B = 1.6 \text{ mA}$

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Fig 10. Selection -16: Collector current as a function of collector-emitter voltage; typical values

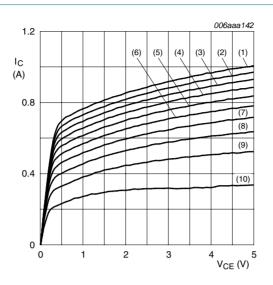


T_{amb} = 25 °C

- (1) $I_B = 13.0 \text{ mA}$
- (2) $I_B = 11.7 \text{ mA}$
- (3) $I_B = 10.4 \text{ mA}$
- (4) $I_B = 9.1 \text{ mA}$
- (5) $I_B = 7.8 \text{ mA}$
- (6) $I_B = 6.5 \text{ mA}$
- (7) $I_B = 5.2 \text{ mA}$
- (8) $I_B = 3.9 \text{ mA}$ (9) $I_B = 2.6 \text{ mA}$
- (10) $I_B = 1.3 \text{ mA}$
- Fig 11. Selection -25: Collector current as a function of collector-emitter voltage; typical values

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 $T_{amb} = 25 \, ^{\circ}C$

- (1) $I_B = 12.0 \text{ mA}$
- (2) $I_B = 10.8 \text{ mA}$
- (3) $I_B = 9.6 \text{ mA}$
- (4) $I_B = 8.4 \text{ mA}$
- (5) $I_B = 7.2 \text{ mA}$
- (6) $I_B = 6.0 \text{ mA}$
- (7) $I_B = 4.8 \text{ mA}$ (8) $I_B = 3.6 \text{ mA}$
- (9) $I_B = 2.4 \text{ mA}$
- (10) $I_B = 1.2 \text{ mA}$

Product data sheet

Fig 12. Selection -40: Collector current as a function of collector-emitter voltage; typical values

8. Package outline

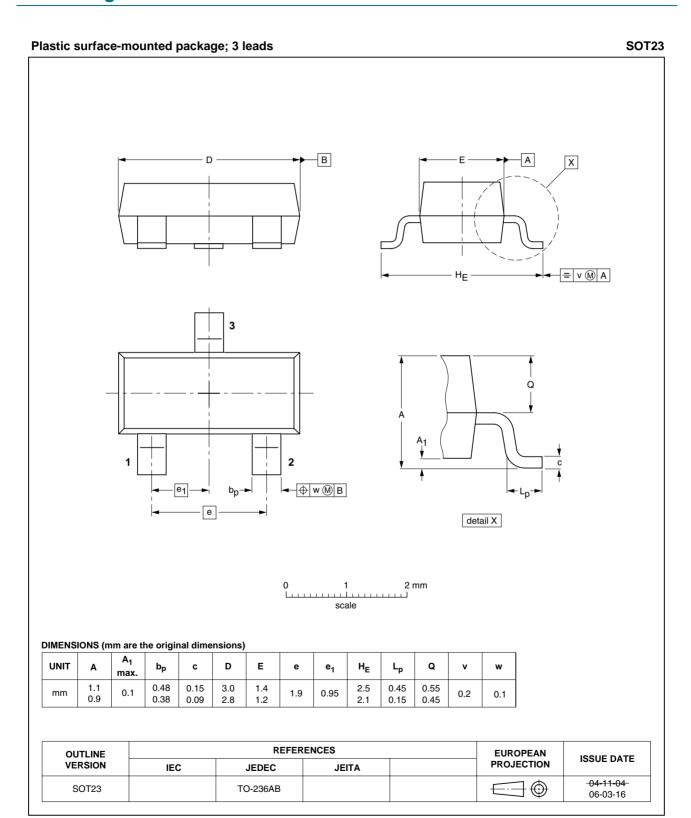


Fig 13. Package outline SOT23 (TO-236AB)

Plastic surface-mounted package; 3 leads

SOT323

В Α X H_{E} = v (M) A **→** | w (M) B е detail X 2 mm scale

OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT323			SC-70			-04-11-04 06-03-16	

e₁

0.65

ΗE

 $L_{\mathbf{p}}$

0.45

Q

w

0.2

0.2

Fig 14. Package outline SOT323 (SC-70)

DIMENSIONS (mm are the original dimensions)

max

0.1

bp

D

2.2

Ε

1.35

1.15

1.3

С

0.25

UNIT

mm

Plastic single-ended leaded (through hole) package; 3 leads

SOT54

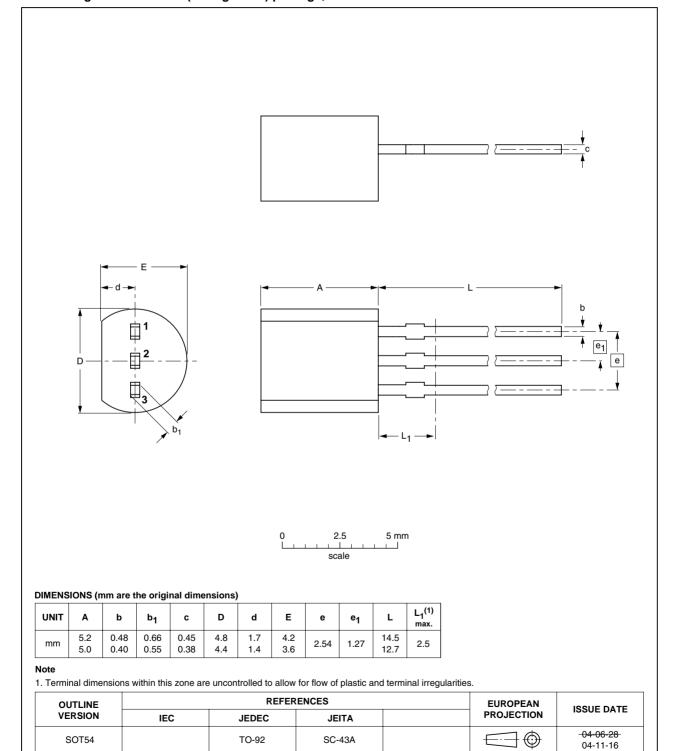


Fig 15. Package outline SOT54 (SC-43A/TO-92)

Plastic single-ended leaded (through hole) package; 3 leads (wide pitch)

SOT54A

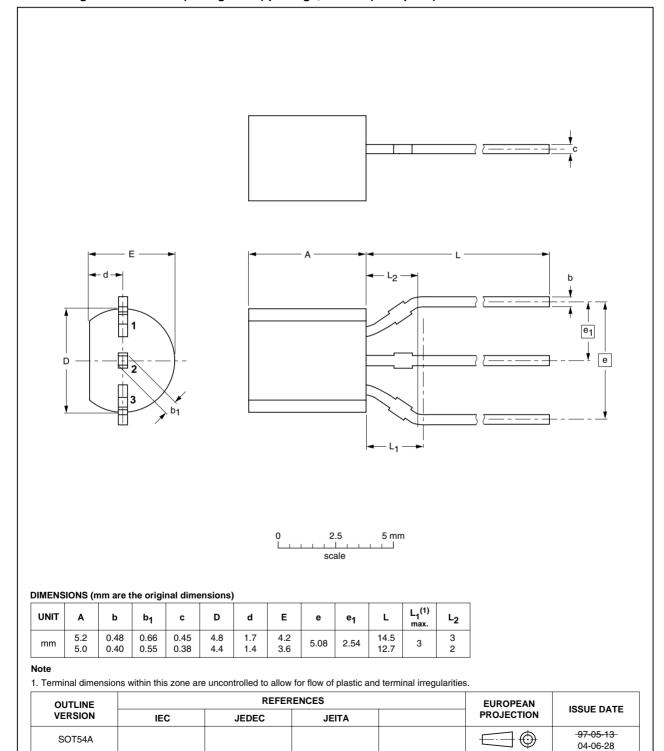


Fig 16. Package outline SOT54A

Plastic single-ended leaded (through hole) package; 3 leads (on-circle)

SOT54 variant

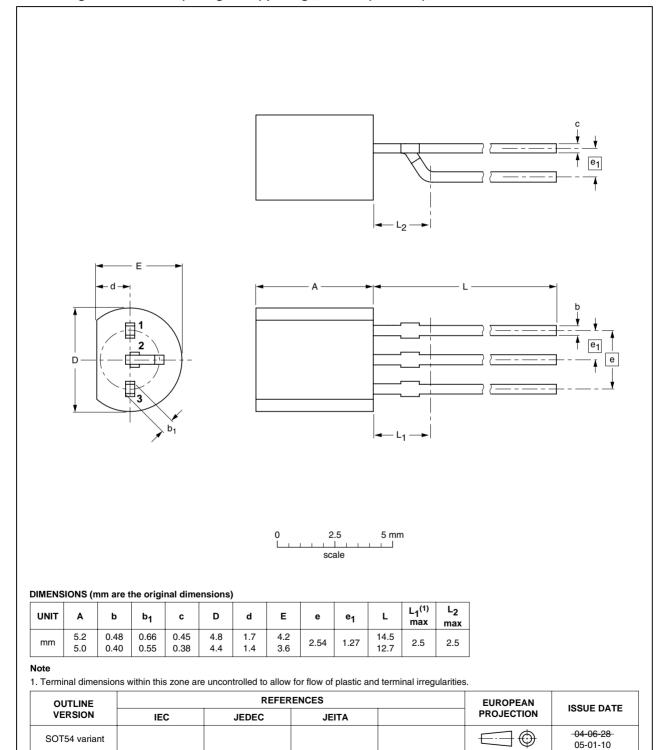


Fig 17. Package outline SOT54 variant

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Packing information

Table 9. **Packing methods**

Product data sheet

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number Package		Description	Packing	Packing quantity		
			3000	5000	10000	
BC817	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
BC817W	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	
BC337	SOT54	bulk, straight leads	-	-412	-	
BC337	SOT54A	tape and reel, wide pitch	-	-	-116	
BC337	SOT54A	tape ammopack, wide pitch	-	-	-126	
BC337	SOT 54 variant	bulk, delta pinning (on-circle)	-	-112	-	

^[1] For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
BC817_BC817W_ BC337_6	20091117	Product data sheet	-	BC817_BC817W_ BC337_5			
Modifications:		et was changed to reflect to respect to the second disclar to the	· · ·				
	• <u>Table 3 "Pinning"</u> : updated						
	 Figure 13 "Package outline SOT23 (TO-236AB)": updated 						
	 Figure 14 "Pa 	ckage outline SOT323 (SC	2-70)": updated				
BC817_BC817W_ BC337_5	20050121	Product data sheet	CPCN200302007F1	BC817_4; BC817W_SER_4; BC337_3			
BC817_4	20040105	Product specification	-	BC817_3			
BC817W_SER_4	20040225	Product specification	-	BC817W_SER_3			
BC337_3	19990415	Product specification	-	BC337_338_CNV_2			

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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12. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

13. Contents

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Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

